# MA3X717D (MA717WA), MA3X717E (MA717WK)

## Silicon epitaxial planar type

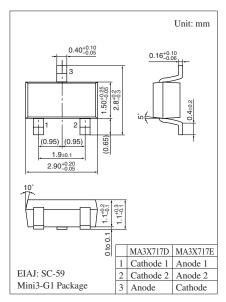
#### For switching

#### ■ Features

- Two MA3X717 (MA717) is contained in one package
- Forward voltage V<sub>F</sub>, optimum for low voltage rectification
- $\bullet$  Low V<sub>F</sub> type of MA3X704D (MA704WA), MA3X704E (MA704WK)
- Optimum for high frequency rectification because of its short reverse recovery time (t<sub>rr</sub>)

### ■ Absolute Maximum Ratings $T_a = 25$ °C

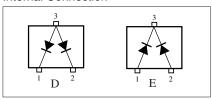
Parameter		Symbol	Rating	Unit
Reverse voltage		$V_R$	30	V
Maximum peak reverse voltage		$V_{RM}$	30	V
Forward current	Single	$I_{F}$	30	mA
	Double		20	
Peak forward current	Single	$I_{FM}$	150	mA
	Double		110	
Junction temperature		T <sub>j</sub>	125	°C
Storage temperature		$T_{stg}$	-55 to +125	°C



#### Marking Symbol

• MA3X717D: M3E • MA3X717E: M3D

#### Internal Connection



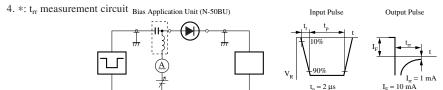
### ■ Electrical Characteristics T<sub>a</sub>=25°C ± 3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{F1}$	$I_F = 1 \text{ mA}$			0.3	V
	$V_{F2}$	$I_F = 30 \text{ mA}$			1.0	
Reverse current	$I_R$	$V_R = 30 \text{ V}$			30	μΑ
Terminal capacitance	C <sub>t</sub>	$V_R = 1 V, f = 1 MHz$		1.5		pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 10 \text{ mA}$		1.0		ns
		$I_{rr} = 1 \text{ mA}$ , $R_L = 100 \Omega$				
Detection efficiency	η	$V_{IN} = 3 V_{(peak)}$ , $f = 30 MHz$		65		%
		$R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$				

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 2 GHz.

Pulse Generator

(PG-10N)

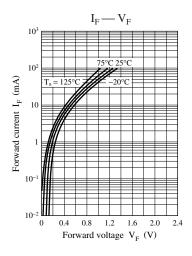


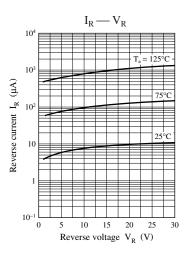
Wave Form Analyzer

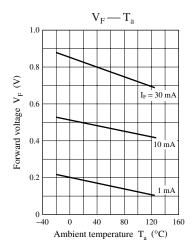
 $R_s = 50 \Omega$  Note) The part numbers in the parenthesis show conventional part number.

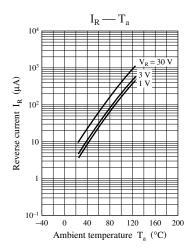
 $\delta = 0.05$ 

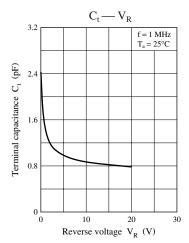
 $R_r = 100 \Omega$ 











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